Fiber Optic Receiver

OPF500 Series



Features:

- Interfaces with all logic circuits
- Two output options
- Optimized for fiber optic applications using 50 to 200 micron fibers
- Data rate to 200kbps NRZ
- Available with multiple packaging options



Description:

The OPF500 series receiver contains a monolithic integrated circuit which incorporates a photodiode, linear amplifier, a voltage regulator, and a Schmitt trigger on a single silicon chip. These receivers are designed for short haul fiber optic systems using 850 nm LEDs such as Optek's OPF300 series.

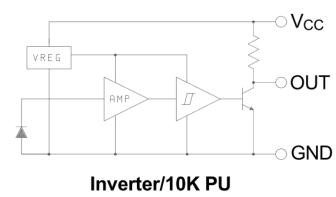
These devices feature TTL/LSTTL compatible logic level output. An internal voltage regulator allows operation with supply voltages ranging from 4.5V to 16V.

Applications:

- Industrial Ethernet equipment
- Copper-to-fiber media conversion
- Intra-system fiber optic links
- Video surveillance systems

Part Ordering Information						
Part Number	Description					
OPF500	Buffer, 10kW Pull-Up Plastic Cap Component					
OPF505	Buffer, 10kW Pull-Up Metal Can Component					
OPF507	Buffer, 10kW Pull-Up Metal ST Receptacle					

Buffer/10K PU



VCC



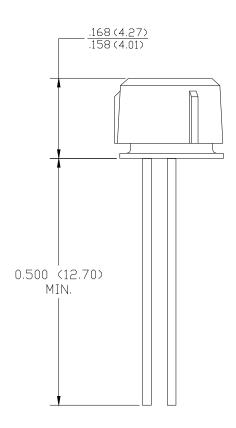


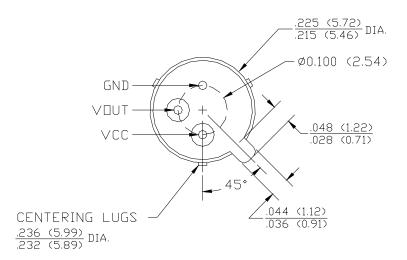
This component is susceptible to damage from electrostatic discharge (ESD). Normal static precautions should be taken in handling and assembly of this component to prevent ESD damage or degradation.

General Note TT Electronics reserves the right to make changes in product specification without



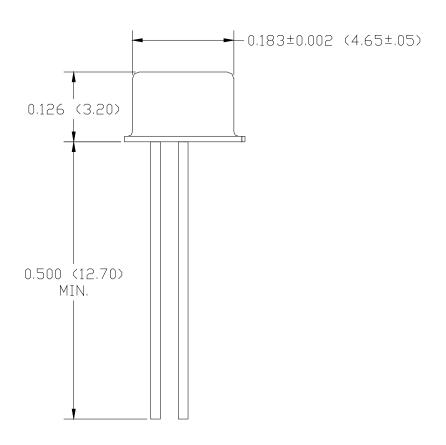
Mechanical Outline-OPF500

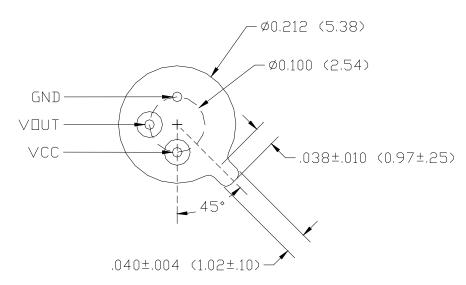






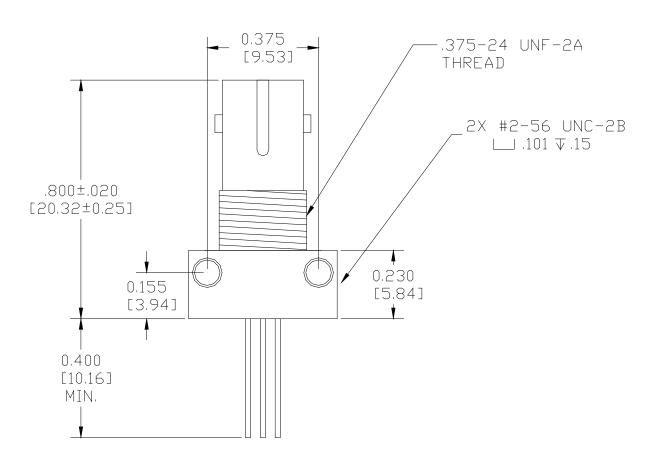
Mechanical Outline-OPF505

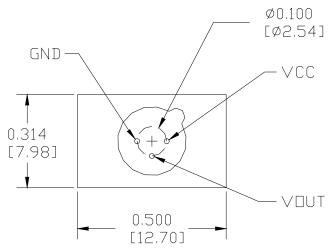






Mechanical Outline-OPF507





Fiber Optic Receiver

OPF500 Series



Electrical Specifications

Absolute Maximum Ratings (T_A = 25° C unless otherwise noted)

Storage Temperature	65° C to +100° C
Operating Temperature	-40° C to +85° C
Lead Soldering Temperature (for 10 seconds)	260° C
Supply Voltage	18 V
Sinking Current	16 mA
Power Dissipation	200 mW
Open Collector Power Distribution	40mW
Voltage at Output	30 V

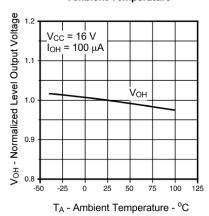
Electrical Characteristics (T_A = 25° C unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	МАХ	UNITS	TEST CONDITIONS	
V _{cc}	Supply Voltage	4.5		16.0	V		
V _{OH}	High Level Output Voltage	VCC - 1.5			V	Buffer: $P_{IN} > 2.0 \mu W$ Inverter: $P_{IN} < 0.1 \mu W$	
V _{OL}	Low Level Output Voltage			0.4	V	Buffer: P _{IN} < 0.1 μW Inverter: P _{IN} > 2.0 μW	
I _{cc}	Supply Current		5.0	12.0	mA	No output load	
P _{IN}	Input Sensitivity			2.0	μW	$\lambda_p = 850 \text{ nm}$	
t _r	Rise Time			300 100	ns	Buffer Inverter	P _{IN} = 1.5 μW (peak)
t _f	Fall Time			300 100	ns	Buffer Buffer	V _{CC} = 5.0 V
BW	Bandwidth	100			kHz	P _{IN} > 2.0 μW, 50% duty cycle	
PWD	Pulse Width Distortion		±10		%	1 μW < P _{IN} < 100 μW, <i>f</i> = 20 kHz 50% duty cycle	

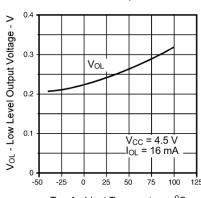


Performance

High Level Output Voltage vs Ambient Temperature



Low Level Output Voltage vs Ambient Temperature



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